

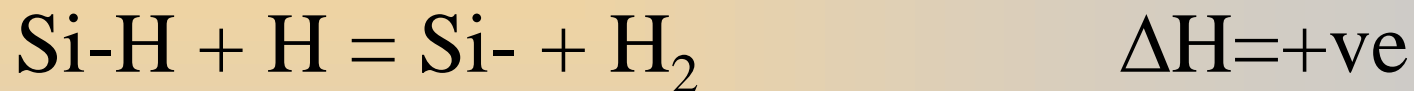
# *nc-Si based Solar Cells*

1. Pressure dependence of nc-Si cells (50 min.)
2. 0.25, 45 and 460cm<sup>2</sup> a-Si/nc-Si tandem cells
3. Degradation behavior of a-Si vs. a-Si/nc-Si
4. Degradation of nc-Si cells vs.  $V_{oc}$  & H-diln.

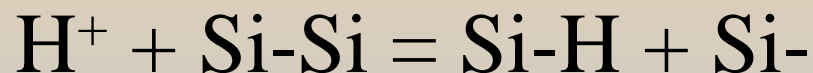


# *Hydrogen atoms and ions*

- ★ Hydrogen atom recombination on surface provides local thermal energy (E-R Process)

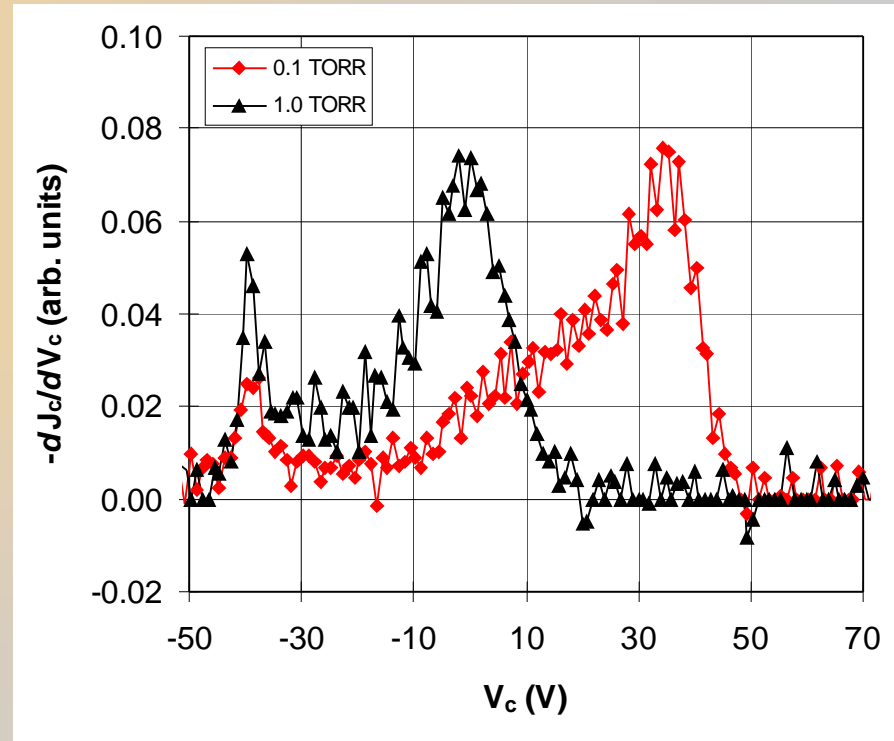
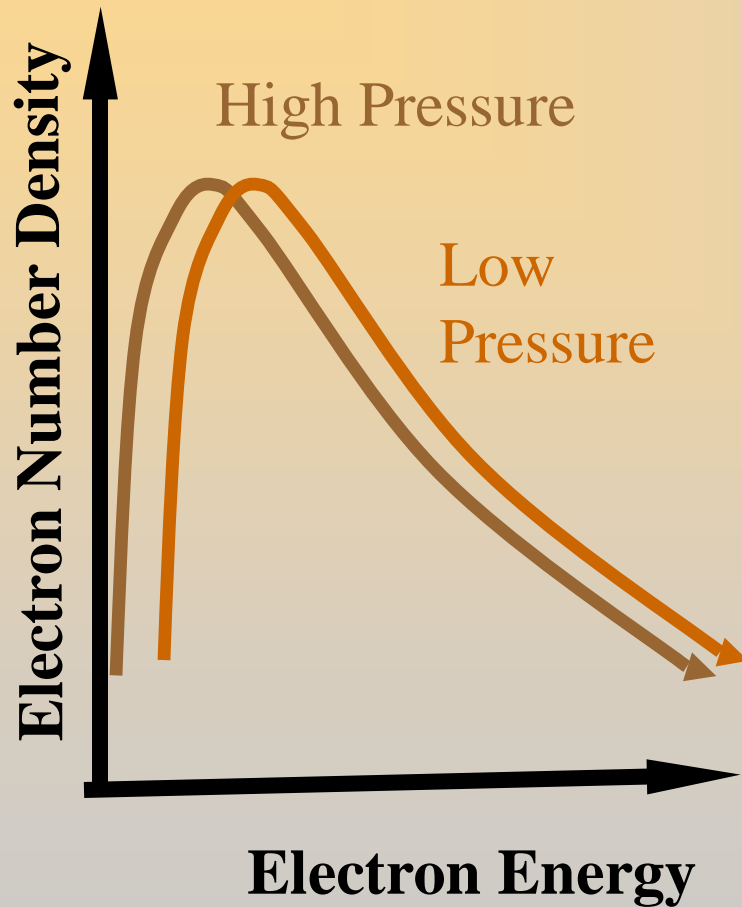


- ★ Hydrogen ions interrupt growth of crystallites



G. Ganguly, M. Fukawa, T. Ikeda and A. Matsuda, J. Non-Cryst Solids 227-230 (1998)

# Hydrogen Atom vs. Ion

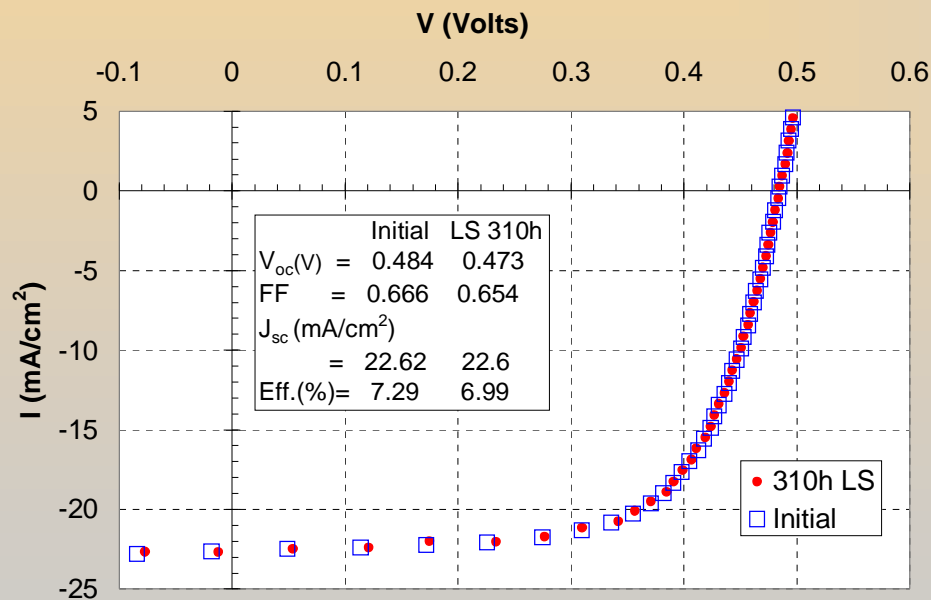


B. Yan, J. Yang, S. Guha and  
A. Gallagher, MRS 557 (1999) 115

**UNI-SOLAR**  
United Solar Ovonic

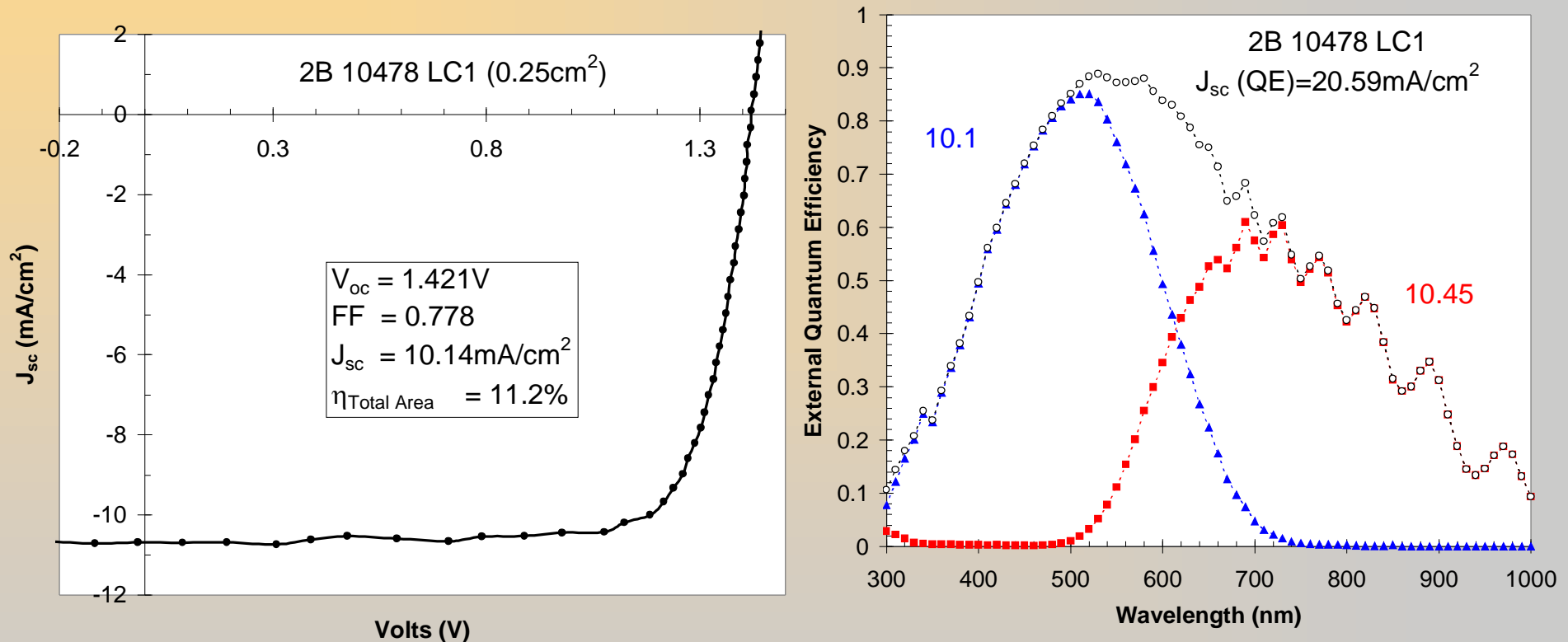
# Pressure:nc-Si cells (~50mins.)

Cell #	Area (cm <sup>2</sup> )	V <sub>oc</sub> (V)	FF	Pressure (Torr)	J <sub>sc</sub> (mA/cm <sup>2</sup> )	Efficiency (%)
10138 LC1	0.25	0.336	0.407	Low	18.02	2.46
10153 LC1	0.25	0.460	0.644	Medium	20.90	6.19
10192 LC1	0.25	0.484	0.666	High	22.62	7.29



★ The performance improves with increasing pressure

# *a-Si/nc-Si (~50mins.) Tandem Cells*



★ We have been able to obtain a total area efficiency of 11.2%

# Degradation of 0.25 cm<sup>2</sup> a-Si/nc-Si(50mins.) Tandem Cells

Run	State	Cell	Filter	V <sub>oc</sub>	FF	J <sub>sc</sub> -Top (mA/cm <sup>2</sup> )	J <sub>sc</sub> -Bot (mA/cm <sup>2</sup> )	η (%)
10478 LC1	Initial	32	AM 1.5	1.42	0.778	10.14	10.45	11.2
	1002h	32	AM 1.5	1.39	0.725	9.9	10.4	10.0
	<i>Degr. (%)</i>			2.3	6.8	2.0	0.4	10.7
10485 LC1	Initial	32	AM 1.5	1.4	0.778	10.45	10.24	11.16
	1002h	32	AM 1.5	1.38	0.742	10.33	10.4	10.57
	<i>Degr. (%)</i>			1.5	4.6	1.2	-1.5	5.3

- ★ Best Stable Efficiency is >10%
- ★ Degradation is 5-10%

## *a-Si / nc-Si (50min.) Tandem cells*

*45 cm<sup>2</sup>  
and  
460 cm<sup>2</sup>*

Serial #	Area	V <sub>oc</sub>	FF	J <sub>sc</sub>	η <sub>Aperture Area</sub>
	(cm <sup>2</sup> )	(V)		(mA/cm <sup>2</sup> )	(%)
10500E3	45	1.429	0.756	10.71	11.62
F1		1.430	0.738	11.46	12.12
F2		1.432	0.736	11.64	12.31
G3		1.441	0.743	11.37	12.22
10582	460	1.440	0.729	10.23	10.76
10583		1.440	0.722	10.13	10.51
10534		1.425	0.694	10.49	10.39
10536		1.422	0.708	10.33	10.43
10587		1.44	0.689	10.66	10.58

★ Initial Efficiency is 12.3% (45cm<sup>2</sup>)  
& 10.8% (460cm<sup>2</sup>)



*a-Si /  
nc-Si  
(50min.)  
45 cm<sup>2</sup>  
and  
460 cm<sup>2</sup>*

Serial #	Area	State	V <sub>oc</sub>	FF	J <sub>sc</sub>	η <sub>Aperture Area</sub>	
	(cm <sup>2</sup> )		(V)		(mA/cm <sup>2</sup> )	(%)	
10490F2	45	Initial	1.425	0.741	11.40	12.07	
		624h	1.400	0.688	11.24	10.87	
G3		Initial	1.437	0.735	11.30	11.97	
		624h	1.420	0.671	11.39	10.86	
10500F1		Initial	1.430	0.738	11.46	12.12	
		624h	1.410	0.670	11.40	10.77	
F2		Initial	1.432	0.736	11.64	12.31	
		624h	1.410	0.680	11.38	10.92	
G3		Initial	1.441	0.743	11.37	12.22	
		624h	1.420	0.686	11.12	10.84	
10534		460	Initial	1.425	0.694	10.49	10.39
			624h	1.410	0.653	10.32	9.51
10536	Initial		1.422	0.708	10.33	10.43	
	624h		1.410	0.652	10.13	9.32	

★ Stable Efficiency is 10.9% (45cm<sup>2</sup>)  
& 9.5% (460cm<sup>2</sup>)





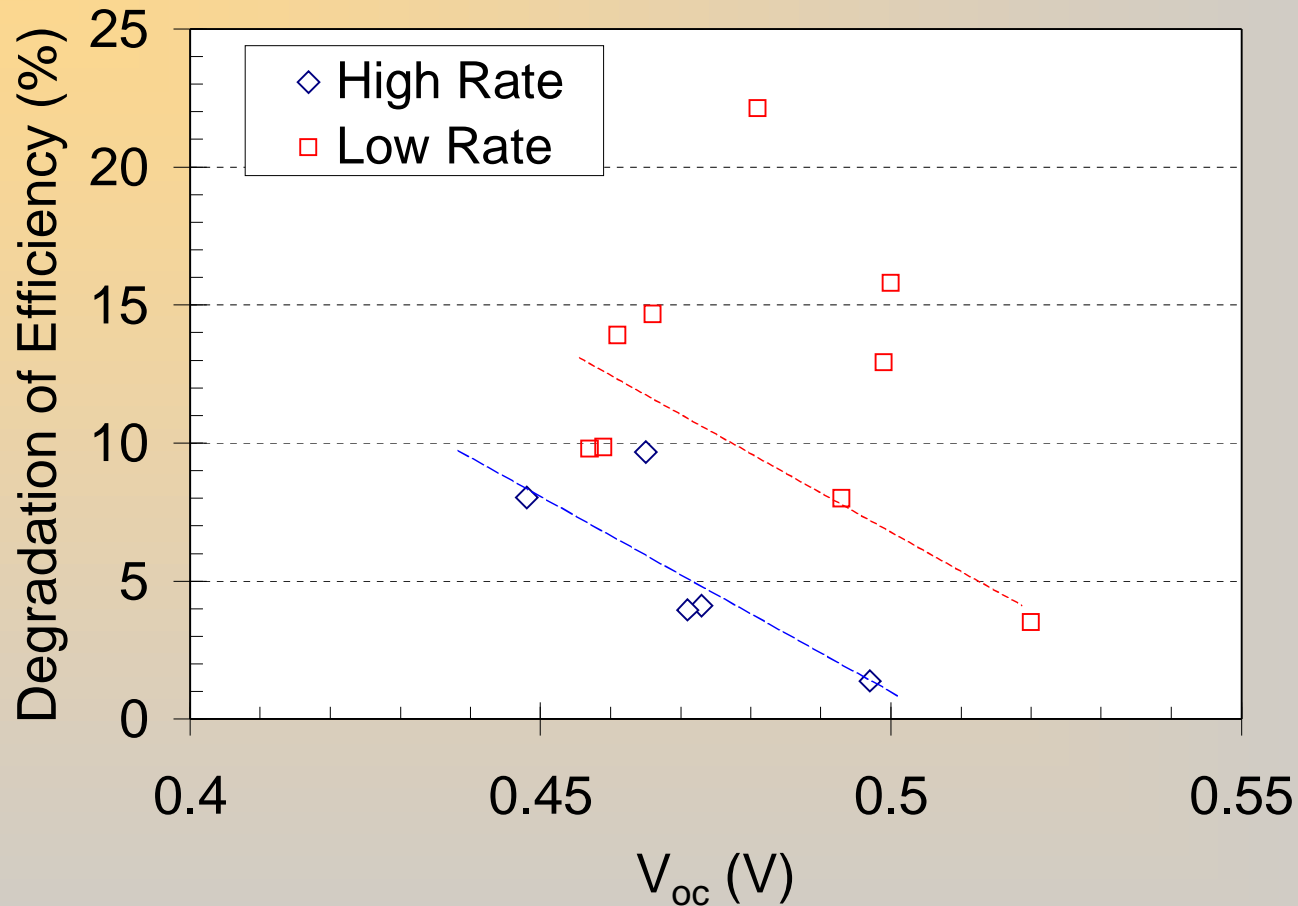
# Degradation of Tandem vs. Top cell

Run	State	Filter	V <sub>oc</sub>	FF	J <sub>sc</sub> -Top (mA/cm <sup>2</sup> )	J <sub>sc</sub> -Bot (mA/cm <sup>2</sup> )	η <sub>Total Area</sub> (%)
10478 LC1	Initial	<585	1.34	0.805			
		>630	1.31	0.756			
		AM 1.5	1.42	0.778	10.14	10.45	11.2
	1002h	<585	1.3	0.788			
		>630	1.25	0.683			
		AM 1.5	1.39	0.725	9.9	10.4	10.0
	<i>Degr.(%)</i>			2.3	6.8	2.0	0.4
10469 A1	Initial	AM 1.5	1.001	0.745	9.79		7.3
	1002h		0.97	0.645	9.42		5.9
	<i>Degr.(%)</i>		3.1	13.4	3.8		19.3

★ a-Si cell FF degrades less in tandem structure than in single cell (0.683 vs. 0.645)

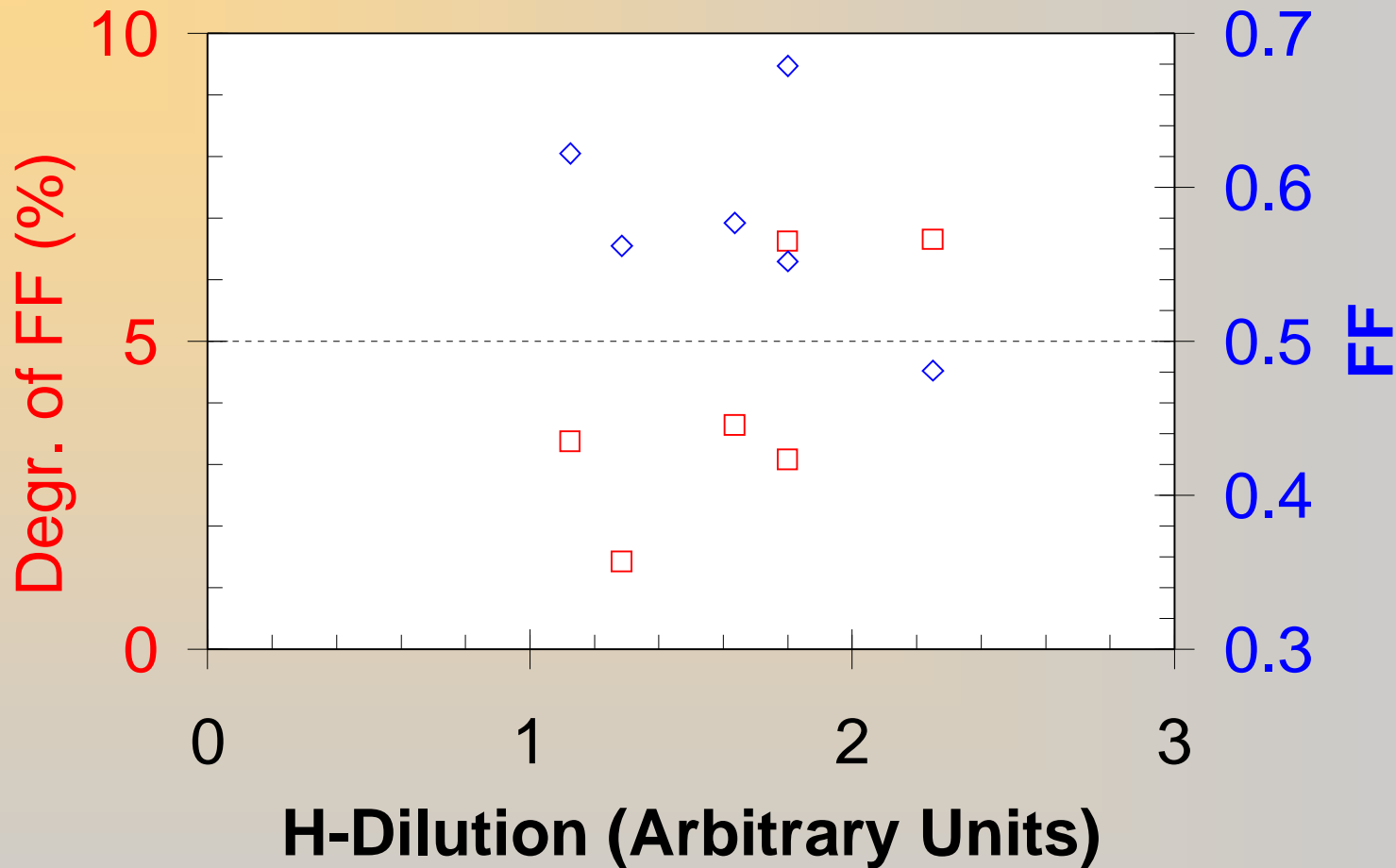


# Degradation of nc-Si cells vs. $V_{oc}$



- ★ Higher  $V_{oc}$  cells are more stable
- ★ Higher Dep. Rate cells are more stable

# *Degradation vs. H-Dilution*

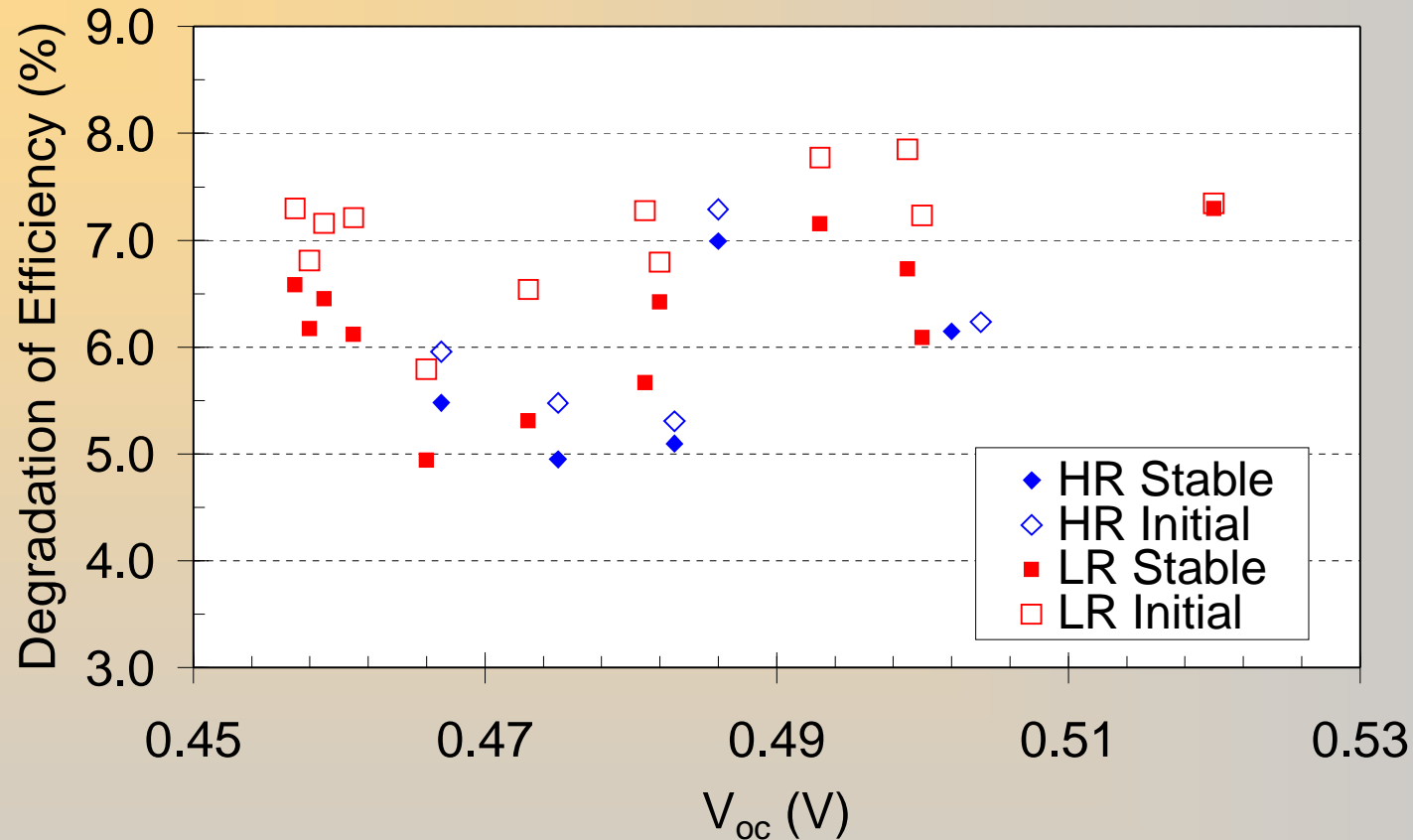


★ FF Decreases but Degradation increases with H-dilution

# Conclusions

- ★ Performance of nc-Si cells improve at higher pressure.
- ★ We have obtained 10.9% (45cm<sup>2</sup>) and 9.5 % (460cm<sup>2</sup>) stable, aperture area efficiency a-Si/nc-Si tandem cells.
- ★ Degradation of nc-Si cells **decreases** with **decreasing** H-dilution and with **increasing**  $V_{oc}$  (closer to transition region)
- ★ Top cell degrades less in a-Si/nc-Si tandem structure than as a single on SS.

# *Initial and LS Efficiencies*



★ The lower rate cells have higher initial efficiencies but degrade more than higher rate ones